MOSFET – Single, N-Channel, SOT-23 30 V, 2.1 A

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc-dc converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- MV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	bol Value		
Drain-to-Source Voltage		V _{DSS}	30	V		
Gate-to-Source Voltage		V _{GS}	±20	V		
Continuous Drain	Steady State	$T_A = 25^{\circ}C$	Ι _D	2.1	А	
Current R _{θJL}		$T_A = 85^{\circ}C$		1.5		
Power Dissipation $R_{\theta JL}$	Steady State	$T_A = 25^{\circ}C$	PD	0.69	W	
Continuous Drain Current (Note 1)	Steady State	$T_A = 25^{\circ}C$	ID	1.6	А	
		$T_A = 85^{\circ}C$		1.2		
Power Dissipation (Note 1)		T _A = 25°C	PD	0.42	W	
Pulsed Drain Current	t _p = 10 μs		I _{DM}	6.0	А	
ESD Capability (Note 3)	C = 100 pF, RS = 1500 Ω		ESD	125	V	
Operating Junction and Storage Temperature		T _J , T _{STG}	-55 to 150	°C		
Source Current (Body Diode)		۱ _S	2.1	А		
Lead Temperature for Soldering Purposes (1/8" from case for 10 sec)		ΤL	260	°C		

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit
Junction-to-Foot - Steady State	$R_{\theta JL}$	180	°C/W
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	300	
Junction-to-Ambient - t < 10 s (Note 1)	$R_{\theta JA}$	250	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	400	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 650 mm², 1 oz. Cu pad size.

2. Surface-mounted on FR4 board using 50 mm², 1 oz. Cu pad size.

3. ESD Rating Information: HBM Class 0.

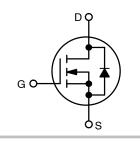


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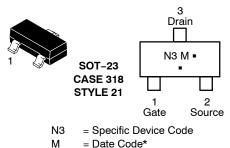
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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
30 V	80 mΩ @ 10 V	2.1 A
	125 mΩ @ 4.5 V	





MARKING DIAGRAM/ PIN ASSIGNMENT



= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MGSF1N03LT1G	SOT-23 Pb-Free	3000 / Tape & Reel
MGSF1N03LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
MVGSF1N03LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage (V_{GS} = 0 Vdc, I _D = 10 μ Adc)		V _{(BR)DSS}	30	-	-	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}$)		I _{DSS}	-		1.0 10	μAdc
Gate-Body Leakage Current (V _{GS} = \pm 20 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	_	-	±100	nAdc
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \ \mu Adc$)		V _{GS(th)}	1.0	1.7	2.4	Vdc
Static Drain-to-Source On-Resistance (V_{GS} = 10 Vdc, I_D = 1.2 Adc) (V_{GS} = 4.5 Vdc, I_D = 1.0 Adc)		r _{DS(on)}	-	0.08 0.125	0.10 0.145	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = 5.0 Vdc)	C _{iss}	-	140	-	pF
Output Capacitance	(V _{DS} = 5.0 Vdc)	C _{oss}	_	100	-	
Transfer Capacitance	(V _{DG} = 5.0 Vdc)	C _{rss}	-	40	-	
SWITCHING CHARACTERISTICS (N	lote 5)					
Turn-On Delay Time		t _{d(on)}	-	2.5	-	ns
Rise Time	(V _{DD} = 15 Vdc, I _D = 1.0 Adc,	t _r	-	1.0	-	
Turn-Off Delay Time	$R_L = 50 \Omega$)	t _{d(off)}	-	16	-]
Fall Time		t _f	_	8.0	-	1
Gate Charge (See Figure 6)		QT	_	6000	-	рС
SOURCE-DRAIN DIODE CHARACT	ERISTICS			•		
Continuous Current		ا _S	-	-	0.6	Α
Pulsed Current		I _{SM}	_	-	0.75	
Forward Voltage (Note 5)		V _{SD}	_	0.8	_	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
4. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2%.
5. Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS

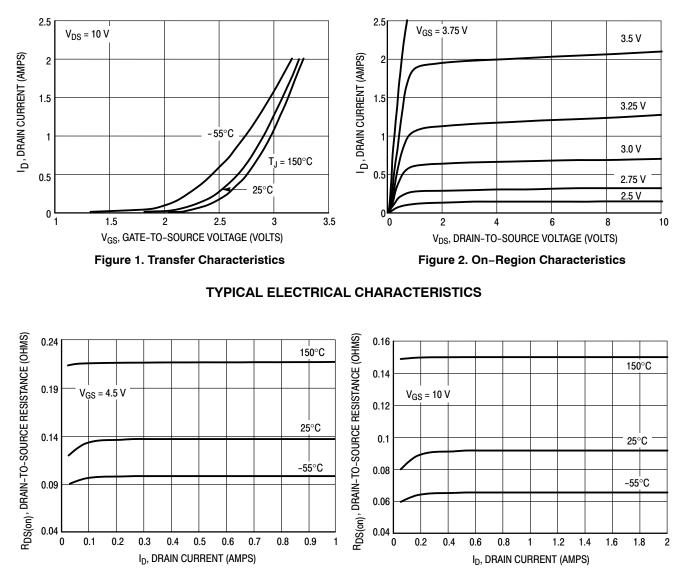


Figure 3. On-Resistance versus Drain Current

Figure 4. On-Resistance versus Drain Current

TYPICAL ELECTRICAL CHARACTERISTICS

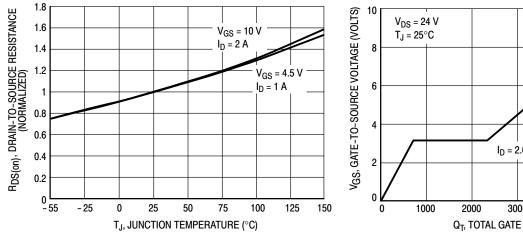


Figure 5. On-Resistance Variation with Temperature

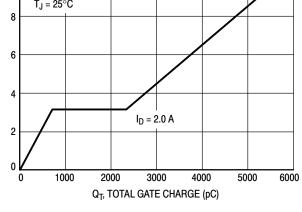


Figure 6. Gate Charge

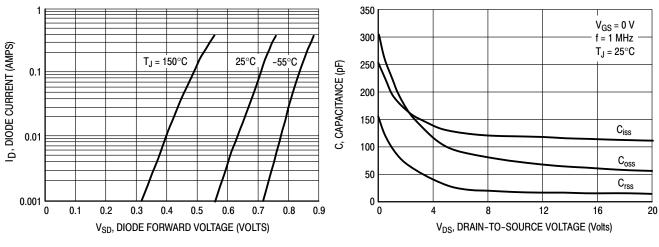
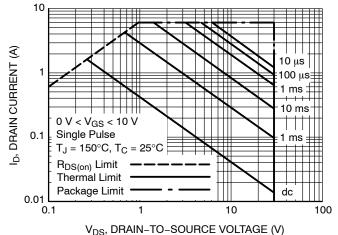


Figure 7. Body Diode Forward Voltage

Figure 8. Capacitance

TYPICAL ELECTRICAL CHARACTERISTICS



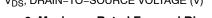
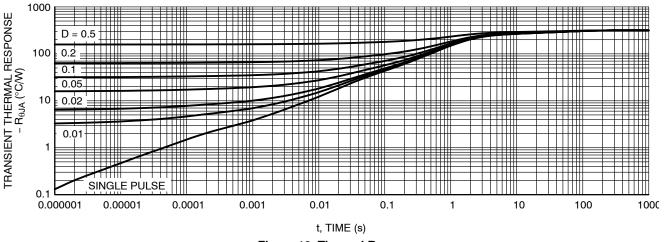


Figure 9. Maximum Rated Forward Biased Safe Operating Area









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